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|  | <h2 style="color: #E67E22;">JAN1N5806US</h2> | |
| | Manufacturer Part Number: | JAN1N5806US |
|  | Manufacturer/Brand: | Microsemi |
| | Part of Description: | DIODE GEN PURP 150V 2.5A D5A |
|  | Datasheets: |  JAN1N5806US.pdf |
| | RoHs Status: | Contains lead / RoHS non-compliant |
| <p>Image may be representation. See specs for product details.</p> | Stock Condition: | New original, Stock Available. |
| | Ship From: | Hong Kong |
| | Shipment Way: | DHL/Fedex/TNT/UPS/EMS |

Specifications

| | |
|-----------------------------------|---|
| Part Number | JAN1N5806US |
| Manufacturer | Microsemi |
| Description | DIODE GEN PURP 150V 2.5A D5A |
| Category | Discrete Semiconductor Products > Diodes - Rectifiers - |
| Part Status | Require For Quote & Check Stock |
| Voltage - Forward (Vf) (Max) @ If | 975mV @ 2.5A |
| Voltage - DC Reverse (Vr) (Max) | 150V |
| Supplier Device Package | D-5A |
| Speed | Fast Recovery = 200mA (Io) |
| Series | Military, MIL-PRF-19500/477 |
| Reverse Recovery Time (trr) | 25ns |
| Packaging | Bulk |
| Package / Case | SQ-MELF, A |
| Operating Temperature - Junction | -65°C ~ 175°C |
| Mounting Type | Surface Mount |
| Diode Type | Standard |
| Current - Reverse Leakage @ Vr | 1µA @ 150V |
| Current - Average Rectified (Io) | 2.5A |
| Capacitance @ Vr, F | 25pF @ 10V, 1MHz |

JAN1N5806US Electronic Components is 100% New Original from YIC Distributor, Search JAN1N5806US Datasheets, PDF, Inventory at Y-IC.com Online, Order JAN1N5806US Microsemi with Warrantied and Confidence. Ship by DHL/FedEx/TNT/UPS Express. Support Payment with Telegraphic Transfer(T/T) or PayPal.
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